

40V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _C = +25°C
40V	$8.6 m\Omega @ V_{GS} = 10V$	48A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power-management functions
- DC-DC converters

Features and Benefits

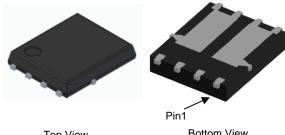
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4007SPDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

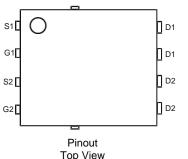
Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)

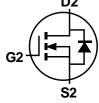
PowerDI5060-8 (Type C)



Bottom View Top View



S1



Equivalent Circuit

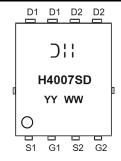
Ordering Information (Note 4)

Dout Number	Dackers	Packing		
Part Number	Package	Qty.	Carrier	
DMTH4007SPDQ-13	PowerDI5060-8 (Type C)	2,500	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



⊃\\ = Manufacturer's Marking H4007SD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024)WW = Week (01 to 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	40	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6), $V_{GS} = 10V$ $T_C = +25^{\circ}C$ $T_C = +100^{\circ}C$		Ι _D	48 34	А	
Continuous Drain Current (Note 5), V _{GS} = 10V Steady State		T _A = +25°C T _A = +100°C	lo	12.5 9.0	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	192	Α		
Maximum Continuous Body Diode Forward Current (Note 6)			Is	34	Α
Avalanche Current, L = 0.1mH			las	20	Α
Avalanche Energy, L = 0.1mH			Eas	20	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_D	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	57	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	37.5	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	4	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V _{DS} = 32V, V _{GS} = 0V
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)			l .			
Gate Threshold Voltage	Vgs(TH)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	RDS(ON)	_	7.5	8.6	mΩ	V _G S = 10V, I _D = 17A
Diode Forward Voltage	V _{SD}	_	0.85	1.2	V	V _{GS} = 0V, I _S = 17A
DYNAMIC CHARACTERISTICS (Note 8)						·
Input Capacitance	Ciss	_	2,026	_	pF	\/ 20\/ \/ 0\/
Output Capacitance	Coss	_	702	_	pF	$V_{DS} = 30V, V_{GS} = 0V,$ - f = 1MHz
Reverse Transfer Capacitance	Crss	_	84.8	_	pF	1 – 11011 12
Gate Resistance	Rg	_	0.46	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Q _G	_	41.9	_	nC	
Gate-Source Charge	Qgs	_	10	_	nC	V _{DS} = 30V, I _D = 20A, V _{GS} = 10V
Gate-Drain Charge	Q_{GD}	_	11.5	_	nC	
Turn-On Delay Time	t _D (ON)	_	7	_	ns	
Turn-On Rise Time	t _R	_	11.5	_	ns	V _{DD} = 30V, V _{GS} = 10V,
Turn-Off Delay Time	t _{D(OFF)}	_	15.6	_	ns	$I_D = 20A, R_G = 3\Omega$
Turn-Off Fall Time	t _F	_	8.8	_	ns	7
Body Diode Reverse Recovery Time	trr		29.9		ns	L = 200 di/dt = 4000/
Body Diode Reverse Recovery Charge	Q _{RR}	_	23	_	nC	-I _F = 20A, di/dt = 100A/μs

otes: 5. Device mounted on FR-4 substrate PC board, 2oz. copper, with thermal bias to bottom layer 1inch square copper plate.

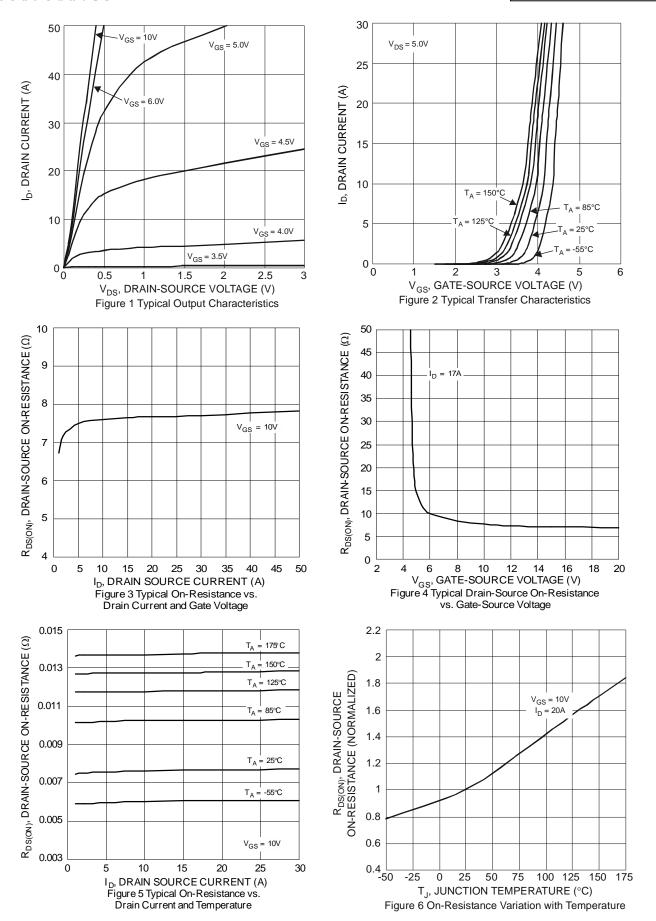
6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Short duration pulse test used to minimize self-heating effect.

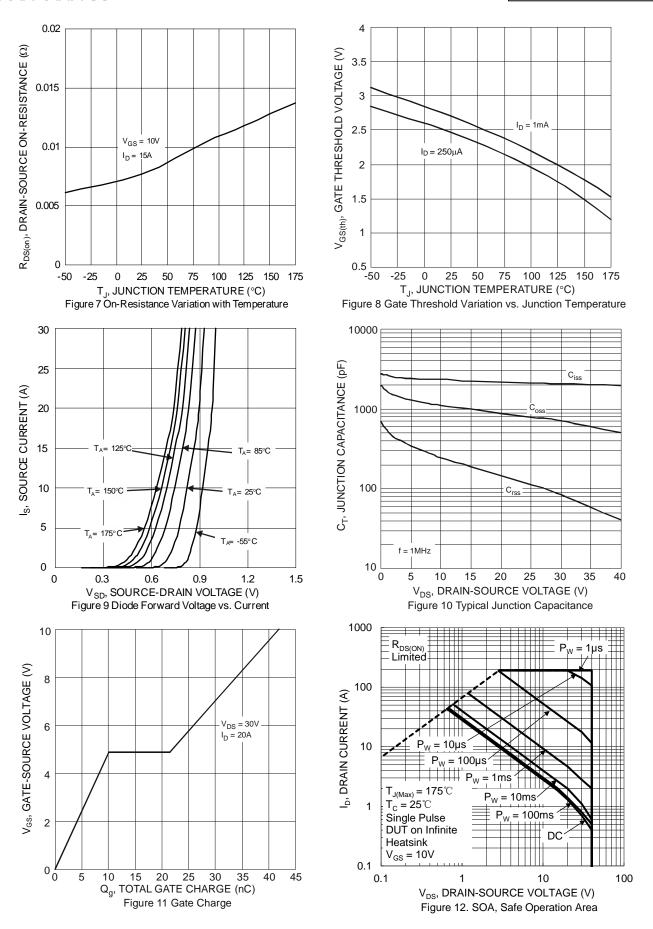
8. Guaranteed by design. Not subject to product testing.



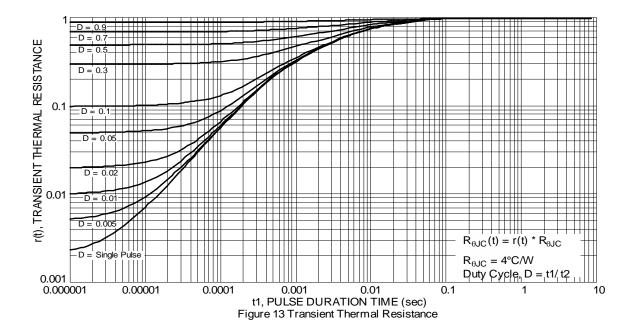










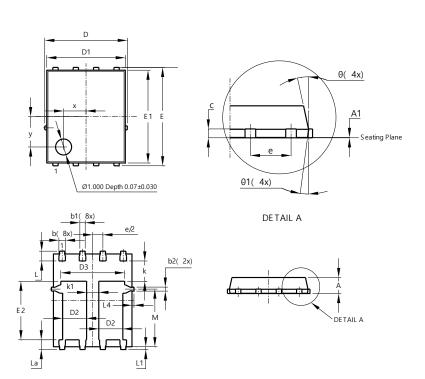




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type C)

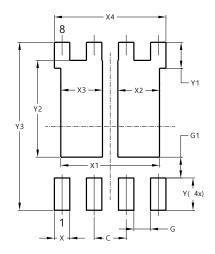


PowerDI5060-8 (Type C)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05	0.02	
b	0.33	0.51	0.41	
b1	0.300	0.366	0.333	
b2	0.20	0.35	0.25	
С	0.23	0.33	0.277	
D	5	.15 BS0)	
D1	4.85	4.95	4.90	
D2	1.40	1.60	1.50	
D3	-	-	3.98	
E	6	.15 BS0)	
E1	5.75	5.85	5.80	
E2	3.56	3.76	3.66	
е	1	.27BSC		
k	-	-	1.27	
k1	0.56	-	-	
L	0.51	0.71	0.61	
La	0.51	0.71	0.61	
L1	0.05	0.20	0.175	
L4	-	-	0.125	
M	3.50	3.71	3.605	
х	-	-	1.400	
у	-	-	1.900	
θ	10°	12° 8°	11°	
θ1	01 6°		7°	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type C)



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	3.910			
X2	1.650			
Х3	1.650			
X4	4.420			
Y	1.270			
Y1	1.020			
Y2	3.810			
Y3	6.610			



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